

# **DATASHEET**

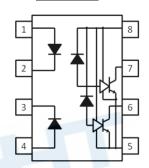
# 8 PIN DIP HIGH SPEED 10MBit/s LOGIC GATE PHOTOCOUPLER EL263X series



### **Features**

- High speed 10Mbit/s
- 10kV/µs min. common mode transient immunity (EL2631)
- Guaranteed performance from -40 to 85°C
- · Logic gate output
- High isolation voltage between input and output (Viso=5000 Vrms)
- Pb free and RoHS compliant.
- UL and cUL approved(No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved

# **Schematic**



A 0.1µF bypass capacitor must be connected between pins 8 and 5 \*3

# Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Cathode
- 4. Anode
- 5. Gnd
- 6. Vout 2
- 7. Vout 1
- $8. \ V_{\text{CC}}$

# **Description**

The EL2630 and EL2631 are consists of an infrared emitting diode optically coupled to a high speed integrated photo detector logic gate with a strobable output. It is packaged in a 8-pin DIP package and available in wide-lead spacing and SMD options.

# **Applications**

- Ground loop elimination
- LSTTL to TTL, LSTTL or 5 volt CMOS
- · Line receiver, data transmission
- Data multiplexing
- Switching power supplies
- Pulse transformer replacement
- Computer peripheral interface
- High speed logic ground isolation

# **Truth Table (Positive Logic)**

Input	Output
Н	L
L	Н



# **Absolute Maximum Ratings (TA=25°C)**

	Parameter	Symbol	Rating	Unit
	Forward current	l <sub>F</sub>	20	mA
Input	Reverse voltage	$V_{R}$	5	V
	Power dissipation	P <sub>D</sub>	40	mW
	Power dissipation	P <sub>C</sub>	60	mW
0.14.1	Output current	lo	50	mA
Output	Output voltage	Vo	7.0	V
	Supply voltage	Vcc	7.0	V
Output Po	ower Dissipation	Po	85	mW
Isolation v	voltage *1	V <sub>ISO</sub>	5000	Vrms
Operating temperature		T <sub>OPR</sub>	-40~+100	°C
Storage to	emperature	T <sub>STG</sub>	-55~+125	°C
Soldering	temperature *2	T <sub>SOL</sub>	260	°C

# Notes:

<sup>\*1</sup> AC for 1 minute, R.H.=  $40 \sim 60\%$  R.H. In this test, pins 1, 2, 3 & 4 are shorted together, and pins 5, 6, 7 & 8 are shorted together.

<sup>\*2</sup> For 10 seconds.



# **Electrical Characteristics (T<sub>A</sub> =-40 to 85°C unless specified otherwise)**

Input

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Forward voltage	$V_{F}$	-	1.4	1.8	V	$I_F = 10$ mA, $T_A = 25$ °C
Reverse voltage	$V_{R}$	5.0	-	-	V	$I_R = 10\mu A$
Temperature coefficient of forward voltage	$\Delta V_F/\Delta T_A$	-	-1.8	-	mV/°C	I <sub>F</sub> =10mA
Input capacitance	$C_{IN}$	-	60	-	рF	V <sub>F</sub> =0, f=1MHz

Output

Parameter	Symbol	Min	Тур.*	Max.	Unit	Condition
High level supply current	Іссн	-	12.5	18	mA	I <sub>F</sub> =0mA, V <sub>CC</sub> =5.5V
Low level supply current	Iccl	-	14.5	21	mA	I <sub>F</sub> =10mA, V <sub>CC</sub> =5.5V

Transfer Characteristics (T<sub>A</sub> =-40 to 85°C unless specified otherwise)

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
HIGH Level Output Current	Іон		2.1	100	μΑ	V <sub>CC</sub> =5.5V, V <sub>O</sub> =5.5V, I <sub>F</sub> =250µA
LOW Level Output Current	VoL	-	0.35	0.6	V	$V_{CC} = 5.5V$ , $I_F=5mA$ , $I_{CL}=13mA$
Input Threshold Current	lғт	-	2.5	5	mA	V <sub>CC</sub> = 5.5V, V <sub>O</sub> =0.6V, I <sub>OL</sub> =13mA

Switching Characteristics (T<sub>A</sub> =-40 to 85°C, V<sub>CC</sub>=5V, I<sub>F</sub>=7.5mA unless specified otherwise)

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Propagation delay time to output High level*4 (Fig.12)	$T_PLH$	-	35	100	ns	$C_L$ = 15pF, $R_L$ =350 $\Omega$ , $T_A$ =25°C
Propagation delay time to output Low level*5 (Fig.12)	$T_{PHL}$	-	40	100	ns	$C_L$ = 15pF, $R_L$ =350 $\Omega$ , $T_A$ =25°C
Pulse width distortion	$ T_{PHL}-T_{PLH} $	-	5	35	ns	$C_L = 15pF, R_L=350\Omega$
Output rise time*6 (Fig.12)	tr	-	40	-	ns	$C_L = 15pF, R_L=350\Omega$
Output fall time* <sup>7</sup> (Fig.12)	t <sub>f</sub>	-	10	-	ns	$C_L = 15pF, R_L=350\Omega$



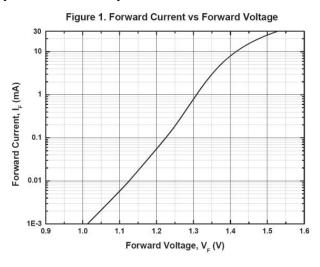
# Switching Characteristics (T<sub>A</sub> =-40 to 85°C, V<sub>CC</sub>=5V, I<sub>F</sub>=7.5mA unless specified otherwise)

Parame	eter	Symbol	Min	Тур.	Max.	Unit	Condition
Mode Transient —— Immunity at	EL2630	- CM <sub>H</sub>	5,000	-	-	V/μS	$\begin{split} I_F &= 0 mA \;,\; V_{CM} = 1 K V_{p\text{-}p}, \\ V_{OH} &= 2.0 V,\; R_L = 350 \Omega, \\ T_A &= 25 ^{\circ} C (Fig.13) \end{split}$
	EL2631	- Civi <sub>H</sub>	10,000	20,000	-	<b>ν</b> /μ <b>3</b>	$\begin{split} I_F &= 0 mA \;,\; V_{CM} = 1 K V_{p\text{-}p}, \\ V_{OH} &= 2.0 V,\; R_L = 350 \Omega, \\ T_A &= 25 ^{\circ} C (Fig.13) \end{split}$
Common Mode Transient	EL2630	- CML	5,000	-	-	V/uS	$\begin{split} I_F &= 7.5 \text{mA}, \ V_{\text{CM}} = 1 \text{KV}_{\text{p-p}}, \\ V_{\text{OL}} &= 0.8 \text{V}, \ R_{\text{L}} = 350 \Omega, \\ T_{\text{A}} &= 25^{\circ} \text{C(Fig.13)} \end{split}$
Immunity at Logic Low *9	EL2631	CIVIL	10,000	20,000	-	V/μS	$I_F = 7.5 \text{mA}, V_{CM} = 1 \text{KV}_{p-p},$ $V_{OL} = 0.8 \text{V}, R_L = 350 \Omega,$ $T_A = 25 \text{°C(Fig.13)}$





# **Typical Electro-Optical Characteristics Curves**



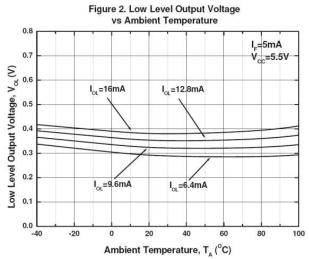
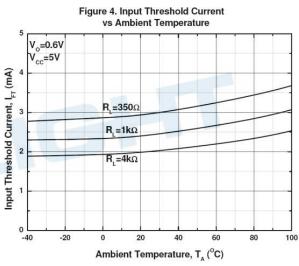
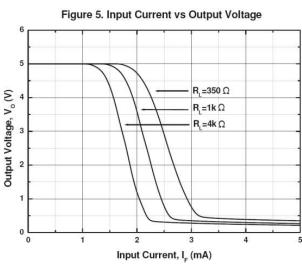
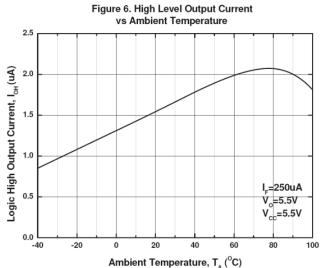


Figure 3. Low Level Output Current vs Ambient Temperature 75 <sub>cc</sub>=5V 70 V<sub>01</sub>=0.6V I<sub>F</sub>=15mA I\_=10mA 15 10 -20 20 100 -40 Ambient Temperature, T<sub>A</sub> (°C)







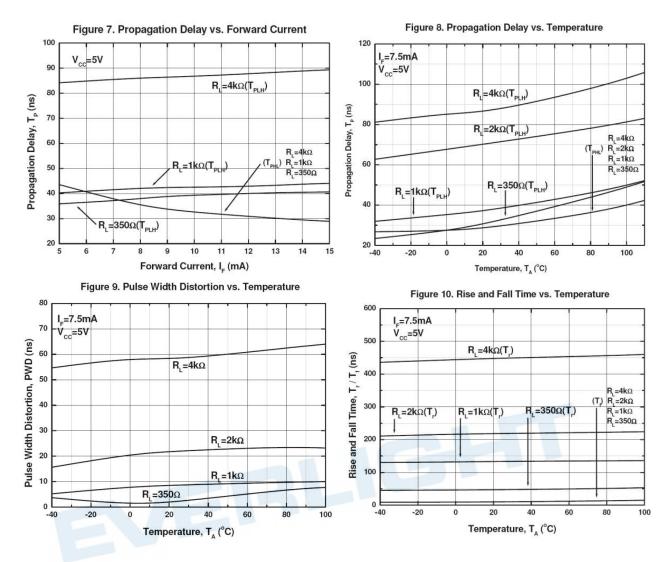
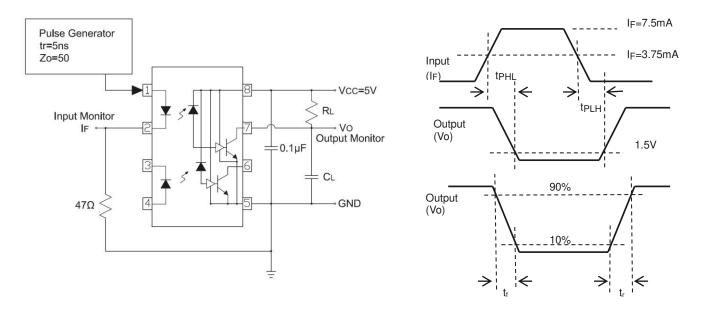


Fig. 11 Test circuit and waveforms for tPHL, tPLH, tr, and tf





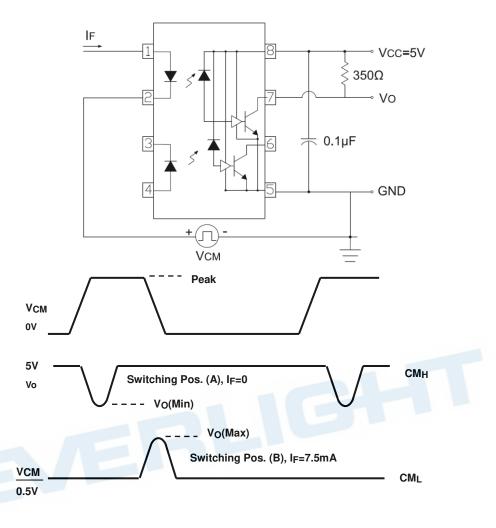


Fig. 12 Test circuit Common mode Transient Immunity

# **Note**

- \*3 The VCC supply must be bypassed by a 0.1µF capacitor or larger. This can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to the package VCC and GND pins
- \*4. tPLH Propagation delay is measured from the 3.75mA level on the HIGH to LOW transition of the input current pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- \*5. tPHL Propagation delay is measured from the 3.75mA level on the LOW to HIGH transition of the input current pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- \*6. tr Rise time is measured from the 90% to the 10% levels on the LOW to HIGH transition of the output pulse.
- \*7. tf Fall time is measured from the 10% to the 90% levels on the HIGH to LOW transition of the output pulse.
- \*8 CMH– The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the HIGH state (i.e., VOUT > 2.0V).
- \*9 CML— The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the LOW output state (i.e., VOUT < 0.8V).



# **Order Information**

# **Part Number**

# EL263XY(Z)-V

# Note

X = (0 or 1) for EL26 part no.

Y = Lead form option (S, S1, M or none)

Z = Tape and reel option (TA, TB or none).

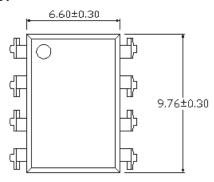
V = VDE (optional)

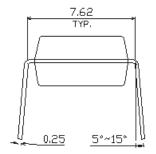
Option	Description	Packing quantity
None	Standard DIP-8	45 units per tube
М	Wide lead bend (0.4 inch spacing)	45 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel
	VERLIGH	

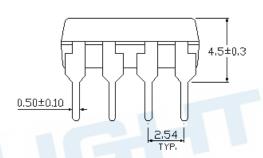


# Package Dimension (Dimensions in mm)

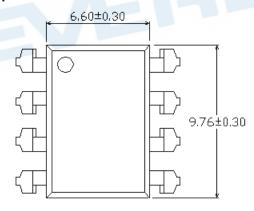
# **Standard DIP Type**

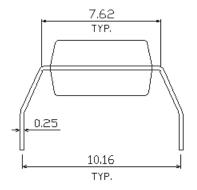


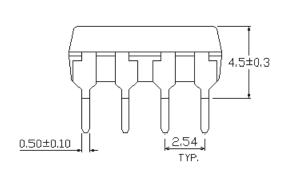




# **Option M Type**

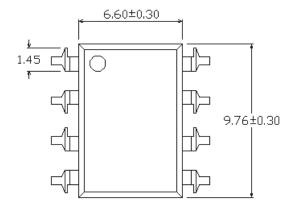


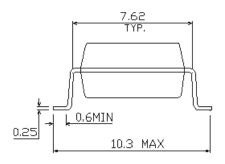


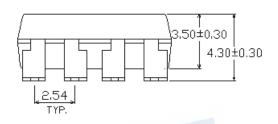




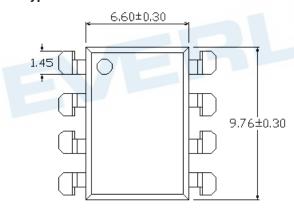
# **Option S Type**

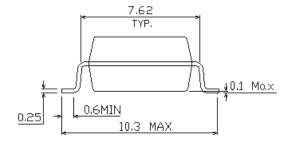


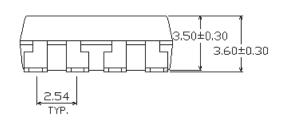




# **Option S1 Type**

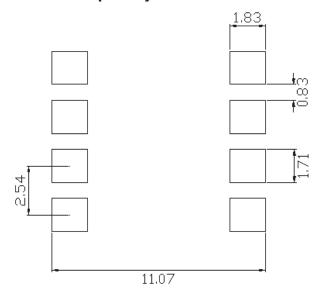








# Recommended pad layout for surface mount leadform

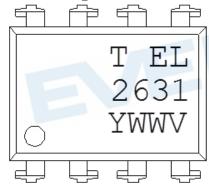


Notes.

Suggested pad dimension is just for reference only.

Please modify the pad dimension based on individual need.

# **Device Marking**



# **Notes**

T denotes Factory

No code: made in China

T : made in Taiwan

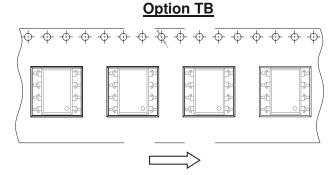
EL denotes EVERLIGHT
2631 denotes Device Number
Y denotes 1 digit Year code
WW denotes 2 digit Week code
V denotes VDE (optional)



# **Tape & Reel Packing Specifications**

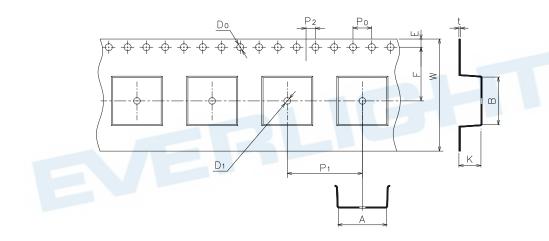
# Option TA Option TA

Direction of feed from reel



Direction of feed from reel

# **Tape dimension**



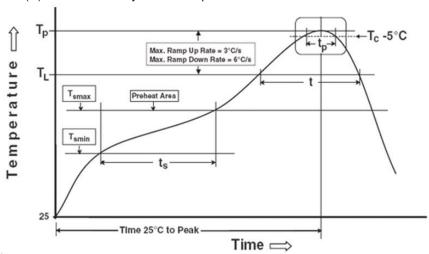
Dimension No.	Α	В	Do	D1	E	F
Dimension(mm)	10.4±0.1	10.0±0.1	1.5+0.1/-0	1.5±0.25	1.75±0.1	7.5±0.1
Dimension No.	Ро	P1	P2	t	W	К
Dimension(mm)	4.0±0.1	12.0±0.1	2.0±0.05	0.4±0.05	16.0±0.3	4.5±0.1



# **Precautions for Use**

# 1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note: Reference: IPC/JEDEC J-STD-020D

3°C/second max

3 times

# **Preheat**

Temperature min  $(T_{smin})$  150°C Temperature max  $(T_{smax})$  200°C Time  $(T_{smin}$  to  $T_{smax})$   $(t_s)$  60-120 seconds

Other

Reflow times

Average ramp-up rate (T<sub>smax</sub> to T<sub>p</sub>)

Liquidus Temperature ( $T_L$ )

217°C

Time above Liquidus Temperature ( $t_L$ )

60-100 sec

Peak Temperature ( $T_P$ )

260°C

Time within 5 °C of Actual Peak Temperature:  $T_P$  - 5°C

Ramp- Down Rate from Peak Temperature

6°C /second max.

Time 25°C to peak temperature

8 minutes max.



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